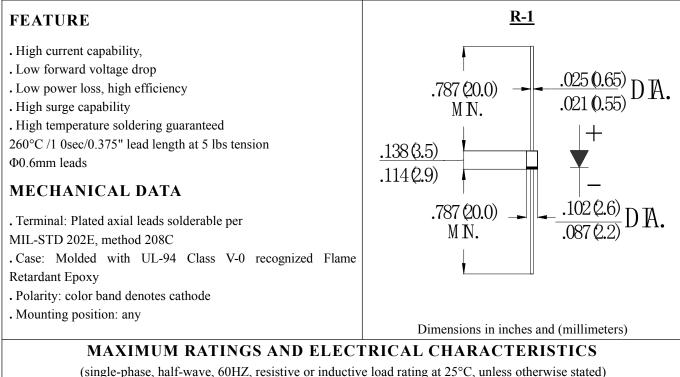


1A7

1.0AMP. SILICON RECTIFIERS



Type Number	SYM	147	units
	BOL	1A/	
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	1000	V
Maximum RMS Voltage	V _{RMS}	700	V
Maximum DC blocking Voltage	V _{DC}	1000	V
Maximum Average Forward Rectified	I _{F(AV)}	1.0	А
Current.375"(9.5mm) lead length @Ta =50°C		1.0	
Peak Forward Surge Current 8.3ms single half	I _{FSM}		А
sine-wave superimposed on rated load (JEDEC		30.0	
method)			
Maximum Forward Voltage at 1.0A DC	V_F	1.0	V
Maximum Forward Voltage at 3.0A DC	V_F	1.3	V
Maximum DC Reverse Current $Ta = 25^{\circ}C$	I_R	5.0	- μΑ
at rated DC blocking voltage $Ta = 100^{\circ}C$		50.0	
Typical Junction Capacitance (Note 1)	CJ	15	pF
Typical Thermal Resistance (Note 2)	R (JA)	50	°C/W
Storage Temperature	T STG	-55 to +150	°C
Operation Junction Temperature	TJ	-55 to +125	°C

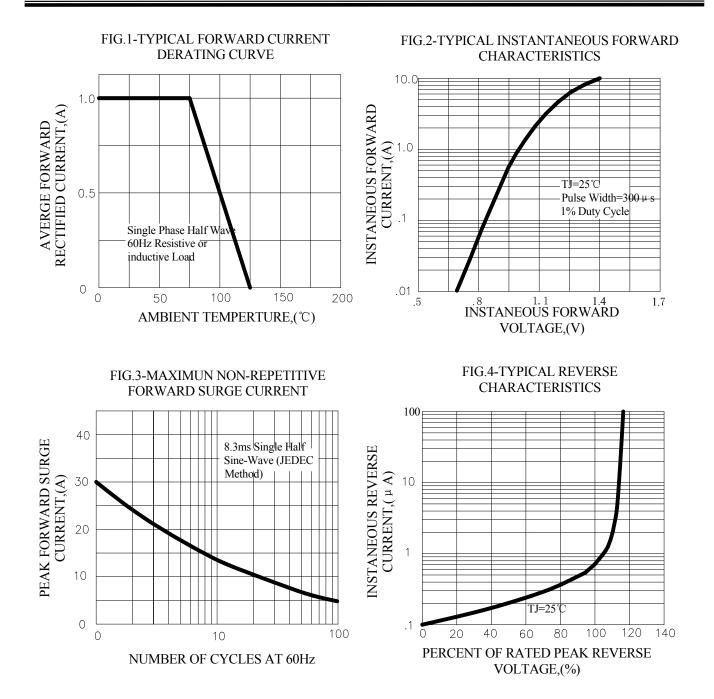
Note:

1. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc

2. Thermal Resistance from Junction to Ambient



RATING AND CHARACTERISTIC CURVES (1A7)



2

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